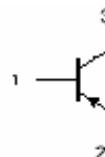


**DESCRIPTION**

- With TO-3 package
- Complement to type MJ15022; MJ15024
- Excellent safe operating area
- High DC current gain
- $h_{FE} = 15$  (Min) @  $I_C = 8$  Adc


**APPLICATIONS**

- Designed for high power audio, disk head positioners and other linear applications

Fig.1 simplified outline (TO-3) and symbol

**Absolute maximum ratings( $T_a = \text{ }^\circ\text{C}$ )**

SYMBOL	PARAMETER		CONDITIONS	VALUE	UNIT
$V_{CBO}$	Collector-base voltage	MJ15023	Open emitter	-350	V
		MJ15025		-400	
$V_{CEO}$	Collector-emitter voltage	MJ15023	Open base	-200	V
		MJ15025		-250	
$V_{EBO}$	Emitter-base voltage		Open collector	-5	V
$I_C$	Collector current			-16	A
$I_{CM}$	Collector current-peak			-30	A
$I_B$	Base current			-5	A
$P_D$	Total power dissipation		$T_C=25$	250	W
$T_j$	Junction temperature			150	
$T_{stg}$	Storage temperature			-65~200	

**THERMAL CHARACTERISTICS**

SYMBOL	PARAMETER	MAX	UNIT
$R_{th j-c}$	Thermal resistance junction to case	0.70	/W

**CHARACTERISTICS**

 T<sub>j</sub>=25 unless otherwise specified

SYMBOL	PARAMETER		CONDITIONS	MIN	TYP.	MAX	UNIT
V <sub>CEO(SUS)</sub>	Collector-emitter sustaining voltage	MJ15023	I <sub>C</sub> =0.1A ; I <sub>B</sub> =0	-200			V
		MJ15025		-250			
V <sub>CEsat-1</sub>	Collector-emitter saturation voltage		I <sub>C</sub> =8A; I <sub>B</sub> =0.8A			-1.4	V
V <sub>CEsat-2</sub>	Collector-emitter saturation voltage		I <sub>C</sub> =16A; I <sub>B</sub> =3.2A			-4.0	V
V <sub>BE</sub>	Base-emitter on voltage		I <sub>C</sub> =8A ; V <sub>CE</sub> =4V			-2.2	V
I <sub>CEO</sub>	Collector cut-off current	MJ15023	V <sub>CE</sub> =150V; I <sub>B</sub> =0			-0.5	mA
		MJ15025	V <sub>CE</sub> =200V; I <sub>B</sub> =0				
I <sub>CEx</sub>	Collector cut-off current	MJ15023	V <sub>CE</sub> =200V; V <sub>BE(off)</sub> =1.5V			-0.25	mA
		MJ15025	V <sub>CE</sub> =250V; V <sub>BE(off)</sub> =1.5V				
I <sub>EBO</sub>	Emitter cut-off current		V <sub>EB</sub> =5V; I <sub>C</sub> =0			-0.5	mA
h <sub>FE-1</sub>	DC current gain		I <sub>C</sub> =8A ; V <sub>CE</sub> =4V	15		60	
h <sub>FE-2</sub>	DC current gain		I <sub>C</sub> =16A ; V <sub>CE</sub> =4V	5			
I <sub>s/b</sub>	Second breakdown collector current with base forward biased		V <sub>CE</sub> =50Vdc,t=0.5 s, V <sub>CE</sub> =80Vdc,t=0.5 s,Nonrepetitive	-5.0 -2.0			A
C <sub>OB</sub>	Output capacitance		I <sub>E</sub> =0 ; V <sub>CB</sub> =10V;f=1.0MHz			500	pF
f <sub>T</sub>	Transition frequency		I <sub>C</sub> =1A ; V <sub>CE</sub> =10V;f=1.0MHz	4			MHz

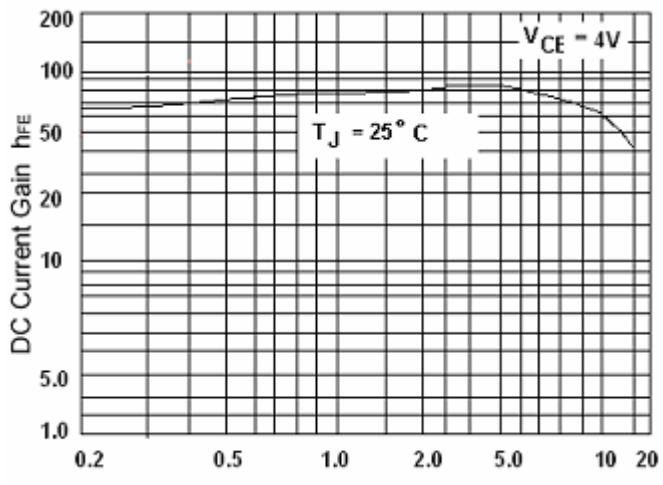


Fig.3 DC current Gain

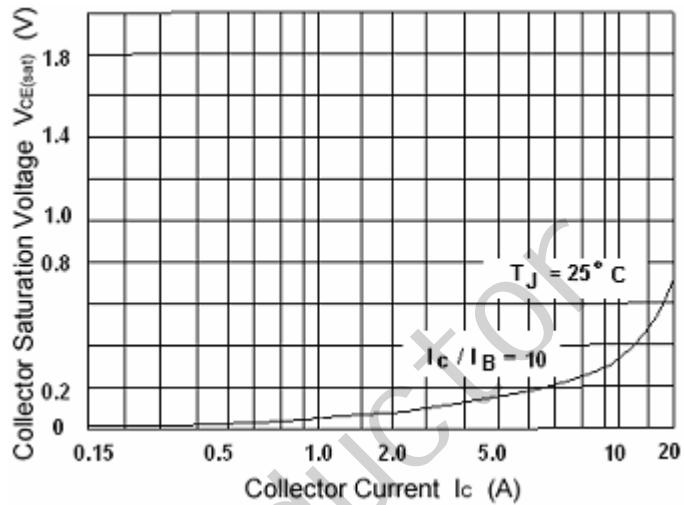


Fig.4 Collector-Emitter Saturation Voltage

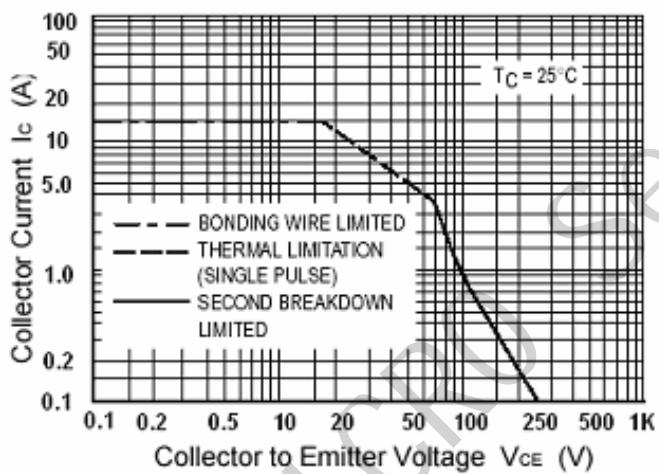


Fig.5 Safe Operating Area

PACKAGE OUTLINE

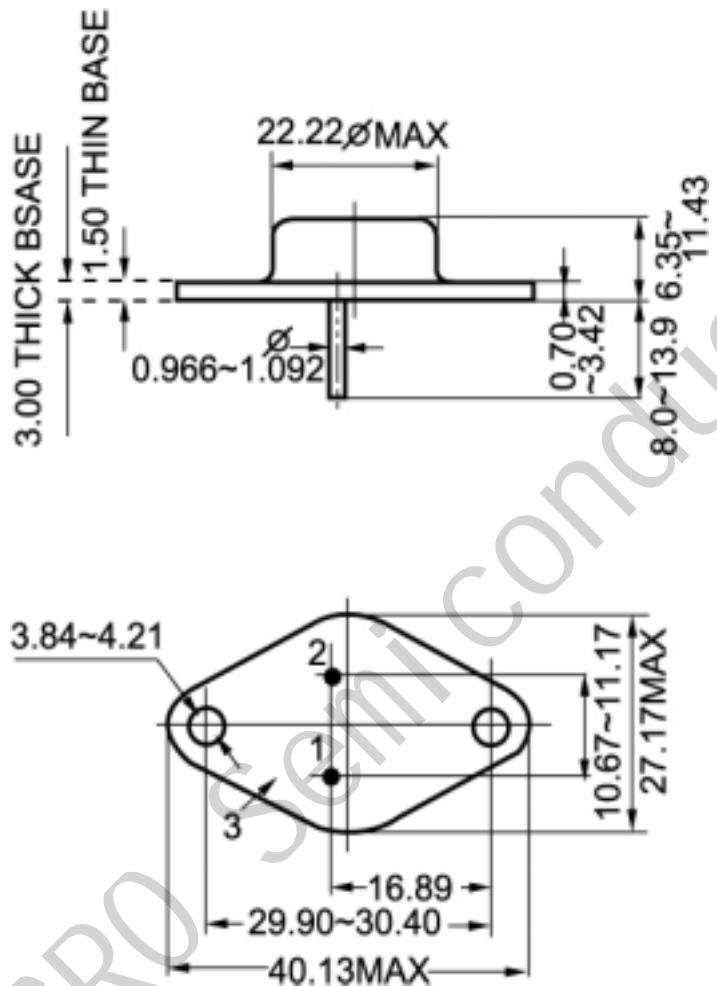


Fig.2 outline dimensions (unindicated tolerance:  $\pm 0.1\text{mm}$ )